PNP/NPN Epitaxial Planar Silicon Transistors



2SA1826/2SC4730

# **100V/3A Switching Applications**

# **Applications**

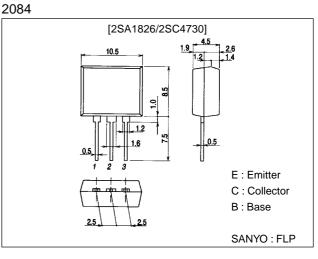
• Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

## **Features**

- $\cdot$  Low collector-to-emitter saturation voltage.
- · High Gain-Bandwidth Product.
- · Excellent linearity of DC Current Gain.
- · Fast switching speed.

# **Package Dimensions**

unit:mm



():2SA1826

# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)120	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(–)100	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(–)6	V
Collector Current	IC		(–)3	A
Collector Current (Pulse)	ICP		(–)6	Α
Base Current	IB		()0.6	Α
Collector Dissipation	PC		1.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)100V, I <sub>E</sub> =0			(–)1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(–)1	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)500mA	100*		400*	
	h <sub>FE2</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)2A	40			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)500mA		(130)		MHz
				180		MHz

 $\ast$  : The 2SA1826/2SC4730 are classified by 500mA  $h_{FE}$  as follows :

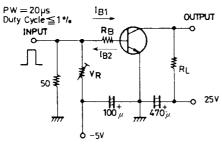
100 R 200 140 S 280 200 T 400

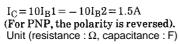
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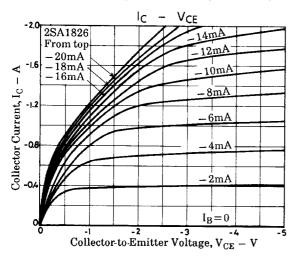
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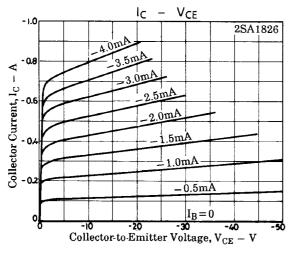
Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Output Capacitance	Cob	V <sub>CB</sub> =(-)10V, f=1MHz		(40)25		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)1.5A, I <sub>B</sub> =(-)0.15A		(–200)	(–500)	mV
				150	400	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)1.5A, I <sub>B</sub> =(-)0.15A		(–)0.9	(–)1.2	mV
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10µA, I <sub>E</sub> =0	(–)120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(−)1mA, R <sub>BE</sub> =∞	()100			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =(-)10μΑ, I <sub>C</sub> =0	(–)6			V
Turn-ON Time	ton	See specified Test Circuit		100		ns
Storage Time	t <sub>stg</sub>	See specified Test Clrcuit		(800)		ns
				900		ns
Fall Time	tf	See specified Test Circuit		50		ns

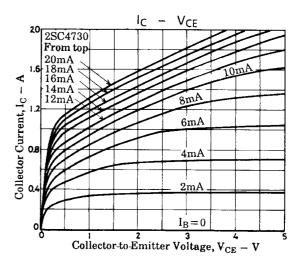
### **Switching Time Test Circuit**

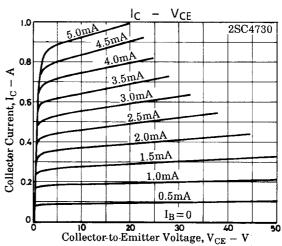




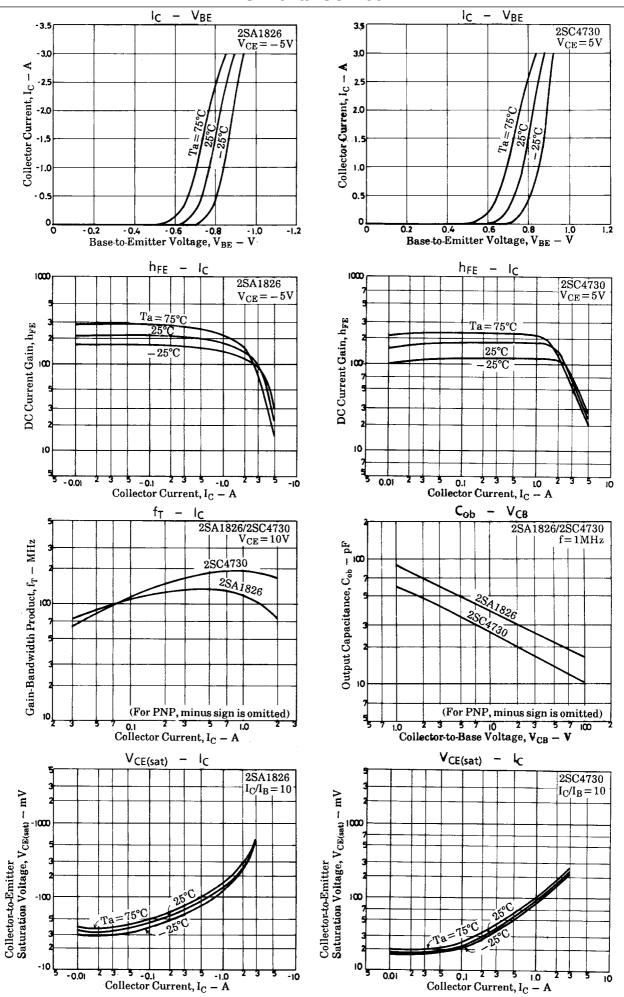


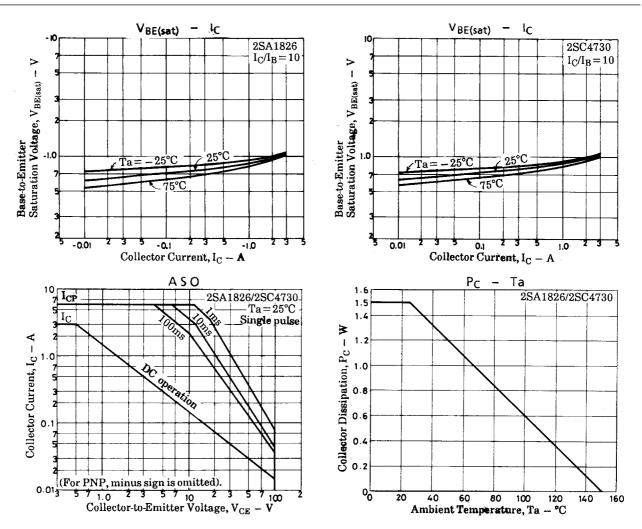






### 2SA1826/2SC4730





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